onsemi

PNP General Purpose Transistor MMBT2907AM3T5G

The MMBT2907AM3T5G device is a spin-off of our popular SOT-23 three-leaded device. It is designed for general purpose amplifier applications and is housed in the SOT-723 surface mount package. This device is ideal for low-power surface mount applications where board space is at a premium.

Features

- Reduces Board Space
- NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q101 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector – Emitter Voltage	V _{CEO}	-60	Vdc
Collector – Base Voltage	V _{CBO}	-60	Vdc
Emitter-Base Voltage	V _{EBO}	-5.0	Vdc
Collector Current – Continuous	Ι _C	-600	mAdc

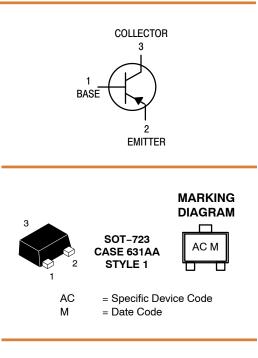
THERMAL CHARACTERISTICS

Characteristic	Symbol	Мах	Unit
Total Device Dissipation FR-5 Board (Note 1) T _A = 25°C Derate above 25°C	P _D	265 2.1	mW mW/°C
Thermal Resistance, Junction-to-Ambient	R_{\thetaJA}	470	°C/W
Total Device Dissipation Alumina Substrate, (Note 2) T _A = 25°C Derate above 25°C	P _D	640 5.1	mW mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	195	°C/W
Junction and Storage Temperature	T _J , T _{stg}	–55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. FR-5 = 1.0 $\stackrel{\scriptstyle \times}{\times}$ 0.75 $\stackrel{\scriptstyle \times}{\times}$ 0.062 in.

2. Alumina = 0.4 \times 0.3 \times 0.024 in. 99.5% alumina.



ORDERING INFORMATION

Device	Package	Shipping [†]
MMBT2907AM3T5G	SOT-723 (Pb-Free)	8000/Tape & Reel
NSVMMBT2907AM3T5G	SOT-723 (Pb-Free)	8000/Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please

refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS				
Collector – Emitter Breakdown Voltage (Note 3) $(I_{\rm C} = -10 \text{ mAdc}, I_{\rm B} = 0)$	V _{(BR)CEO}	-60	-	Vdc
Collector – Base Breakdown Voltage ($I_C = -10 \mu Adc, I_E = 0$)	V _{(BR)CBO}	-60	_	Vdc
Emitter – Base Breakdown Voltage $(I_E = -10 \ \mu Adc, I_C = 0)$	V _{(BR)EBO}	-5.0	-	Vdc
Collector Cutoff Current (V _{CE} = -30 Vdc, V _{EB(off)} = -0.5 Vdc)	ICEX	-	-50	nAdc
Collector Cutoff Current ($V_{CB} = -50$ Vdc, $I_E = 0$) ($V_{CB} = -50$ Vdc, $I_E = 0$, $T_A = 125^{\circ}C$)	I _{CBO}		-0.010 -10	μAdc
Base Cutoff Current ($V_{CE} = -30$ Vdc, $V_{EB(off)} = -0.5$ Vdc)	I _{BL}	-	-50	nAdc

ON CHARACTERISTICS

DC Current Gain	h _{FE}			-
$(I_{C} = -0.1 \text{ mAdc}, V_{CE} = -10 \text{ Vdc})$		75	-	
$(I_{C} = -1.0 \text{ mAdc}, V_{CE} = -10 \text{ Vdc})$		100	-	
$(I_{C} = -10 \text{ mAdc}, V_{CE} = -10 \text{ Vdc})$		100	-	
(I _C = -150 mAdc, V _{CE} = -10 Vdc)		100	300	
(I _C = -500 mAdc, V _{CE} = -10 Vdc) (Note 3)		50	-	
Collector – Emitter Saturation Voltage (Note 3)	V _{CE(sat)}			Vdc
$(I_{C} = -150 \text{ mAdc}, I_{B} = -15 \text{ mAdc})$ (Note 3)	. ,	-	-0.4	
$(I_{C} = -500 \text{ mAdc}, I_{B} = -50 \text{ mAdc})$		-	-1.6	
Base – Emitter Saturation Voltage (Note 3)	V _{BE(sat)}			Vdc
$(I_{C} = -150 \text{ mAdc}, I_{B} = -15 \text{ mAdc})$		-	-1.3	
$(I_{C} = -500 \text{ mAdc}, I_{B} = -50 \text{ mAdc})$		-	-2.6	

SMALL-SIGNAL CHARACTERISTICS

Current – Gain – Bandwidth Product (Notes 3, 4) ($I_C = -50 \text{ mAdc}, V_{CE} = -20 \text{ Vdc}, f = 100 \text{ MHz}$)	f _T	200	_	MHz
Output Capacitance (V _{CB} = -10 Vdc, I _E = 0, f = 1.0 MHz)	C _{obo}	-	8.0	pF
Input Capacitance (V _{EB} = -2.0 Vdc, I _C = 0, f = 1.0 MHz)	C _{ibo}	_	30	

SWITCHING CHARACTERISTICS

Turn–On Time		t _{on}	-	45	
Delay Time	$(V_{CC} = -30 \text{ Vdc}, I_C = -150 \text{ mAdc}, I_{B1} = -15 \text{ mAdc})$	t _d	-	10	
Rise Time		t _r	-	40	
Turn–Off Time		t _{off}	-	100	ns
Storage Time	(V _{CC} = -6.0 Vdc, I _C = -150 mAdc, I _{B1} = I _{B2} = -15 mAdc)	ts	-	80	
Fall Time		t _f	-	30	

 $\begin{array}{ll} \mbox{3. Pulse Test: Pulse Width} \leq 300 \ \mu \mbox{s, Duty Cycle} \leq 2.0\%. \\ \mbox{4. } f_T \mbox{ is defined as the frequency at which } |h_{fe}| \ extrapolates to unity. \end{array}$

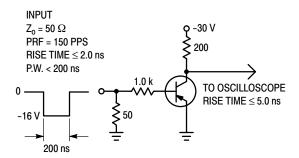
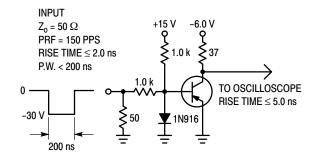


Figure 1. Delay and Rise Time Test Circuit





TYPICAL CHARACTERISTICS

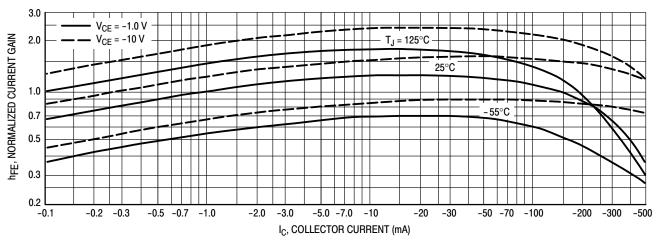
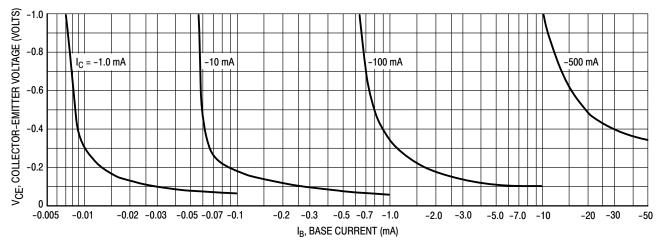
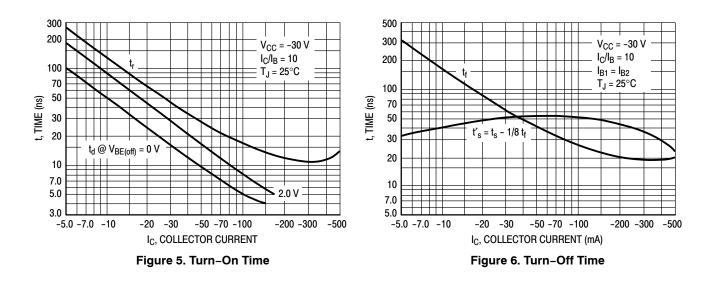
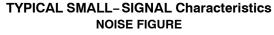


Figure 3. DC Current Gain









 V_{CE} = 10 Vdc, T_A = 25°C

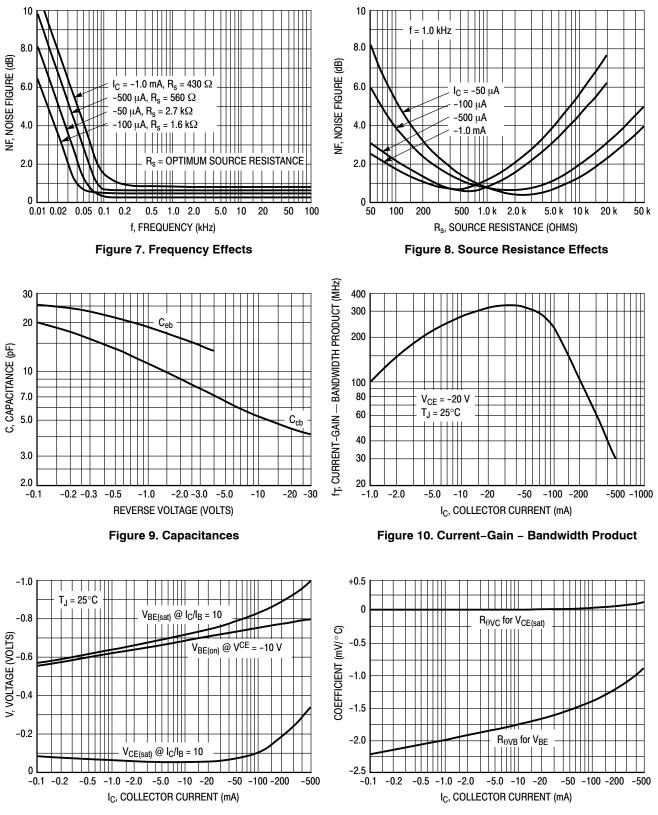


Figure 11. "On" Voltage

Figure 12. Temperature Coefficients



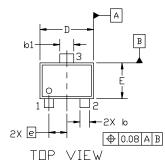


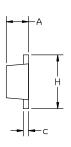
SOT-723 1.20x0.80x0.50, 0.40P CASE 631AA ISSUE E

DATE 24 JAN 2024

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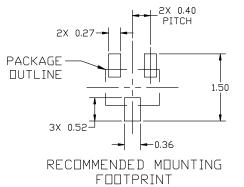
- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2018. CONTROLLING DIMENSION: MILLIMETERS. 1.
- 2.
- MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM З. LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
- DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, 4. PROTRUSIONS OR GATE BURRS.



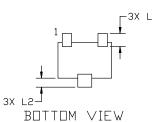


SIDE VIEW

		MILLIMETERS				
	DIM	MIN.	NDM.	MAX.		
1	А	0.45	0.50	0.55		
	b	0.15	0.21	0.27		
	b1	0.25	0.31	0.37		
	С	0.07	0.12	0.17		
	D	1.15	1.20	1.25		
	E	0.75	0.80	0.85		
	e		0.40 BSC			
	Н	1.15	1.20	1.25		
	L	0.29 REF				
	L2	0.15	0.20	0.25		



*For additional information on our Pb-Free strategy and soldering details, please download the DN Semiconductor Soldering and Mounting Techniques Reference Manual, SDLDERRM/D.



GENERIC **MARKING DIAGRAM***



XX = Specific Device Code Μ = Date Code

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

2. EMITTER 2.	II: STYLE 3: ANODE PIN 1. ANODE N/C 2. ANODE CATHODE 3. CATHODE	STYLE 4: PIN 1. CATHODE 2. CATHODE 3. ANODE	STYLE 5: PIN 1. GATE 2. SOURCE 3. DRAIN	
DOCUMENT NUMBER: 98AON12989D			versions are uncontrolled except when acce sions are uncontrolled except when stamped	
DESCRIPTION: SOT-723 1.20x0.80x0.50, 0				PAGE 1 OF 1

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